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View Online at https://aerobasegroup.com/nsn/5961-01-106-8572

Inclosure Material:

Metal

Overall Length:

1.563 inches

Overall Height:

0.662 inches

Overall Width:

1.050 inches

Function For Which Designed:

Switching

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-3

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

120.0 collector to base voltage/static/emitter open and 7.0 emitter to base voltage, static, collector open and 90.0 collector-to-emitter, substaining voltage, base open-circuited

Current Rating Per Characteristic:

50.00 amperes source cutoff current

Power Rating Per Characteristic:

140.0 watts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Terminal Type And Quantity:

1 case and 2 pin

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

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